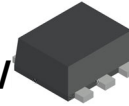


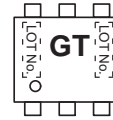
# RF Transistor

8 V47 22 A2.79(f 1 Tf19.754 7TD47:0 I6757 5T/MCH6001/ 59.7543 6f:339. Tm-



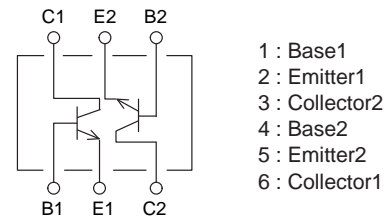
SC 88FL / MCPH6  
CASE 419AS

## MARKING DIAGRAM



GT = Specific Device Code

## ELECTRICAL CONNECTION



	$V_{EBO}$		2	V
Collector Current	$I_C$		150	mA
Collector Dissipation	$P_C$	When mounted on glass epoxy substrate 1 unit	400	mW
Total Dissipation	$P_T$	When mounted on glass epoxy substrate	600	mW
Junction Temperature	$T_J$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## ORDERING INFORMATION

Device	Package	Shipping†
MCH6001-TL-E	MCPH6 / SC-88FL (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

# MCH6001

## ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			Min	Typ	Max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 5\text{ V}, I_E = 0\text{ A}$	–	–	1.0	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 1\text{ V}, I_C = 0\text{ A}$	–	–	1.0	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE} = 5\text{ V}, I_C = 50\text{ mA}$	60	–	150	
Gain–Bandwidth Product	$f_T$	$V_{CE} = 5\text{ V}, I_C = 50\text{ mA}$	13	16	–	GHz
Forward Transfer Gain	$ S_{21e} ^2$	$V_{CE} = 5\text{ V}, I_C = 50\text{ mA}, f = 1\text{ GHz}$	–	16	–	dB
Noise Figure	NF	$V_{CE} = 1\text{ V}, I_C = 10\text{ mA}, f = 1\text{ GHz}$	–	1.2	1.8	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: Pay attention to handling since it is liable to be affected by static electricity due to the high–frequency process adopted.

# MCH6001

## TYPICAL CHARACTERISTICS

$V_{CE}$ , COLLECTOR-TO-EMITTER VOLTAGE (V)

**Figure 1.  $I_C$  vs  $V_{CE}$**

$V_{BE}$ , BASE-TO-EMITTER VOLTAGE (V)

**Figure 2.  $I_C$  vs  $V_{BE}$**

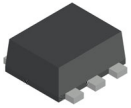
$I_C$ , COLLECTOR CURRENT (mA)

**Figure 3.  $h_{FE}$  vs  $I_C$**

$V_{CB}$ , COLLECTOR-TO

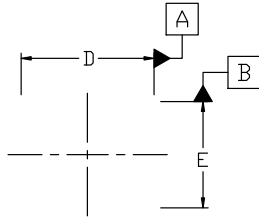
**Figure 4.  $C_{re}$  vs  $V_{CB}$**





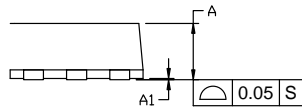
**SC-88FL / MCPH6**  
**CASE 419AS**  
**ISSUE A**

DATE 28 SEP 2022

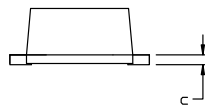


⌀ 0.1 (M) A

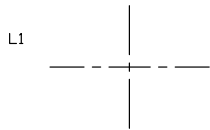
TOP VIEW



SIDE VIEW



FRONT VIEW



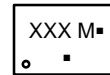
BOTTOM VIEW

NOTES:

1. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE.
2. ALL DIMENSIONS ARE IN MILLIMETERS.
3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND THE BAR PROTRUSIONS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.85	0.90
A1	0.00	---	0.02
b	0.25	0.30	0.40
c	0.12	0.15	0.25
D	1.94	2.00	2.06
E	1.54	1.60	1.66
He	2.05	2.10	2.15
L	0.19	0.25	0.31
L1	0.00	0.07	0.12

**GENERIC MARKING DIAGRAM\***



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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